A nom alous M etal-Insulator Transition in Filled Skutterudite C eO s₄Sb₁₂

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A nom abus metal-insulator transition observed in lled skuttenudite C $eO s_4 Sb_{12}$ is investigated by constructing the electron tight-binding model with the C oulom b repulsion between f electrons. By using the mean eld approximation, magnetic susceptibilities are calculated and the phase diagram is obtained. When the band structure has a sem in etallic character with small electron and hole pockets at and H points, a spin density wave transition with the ordering vector Q = (1;0;0) occurs due to the nesting property of the Ferm i surfaces. M agnetic eld enhances this phase in accord with the experiments.

KEYW ORDS: led-skutterudite compounds, CeOs(Sb12, eld induced metal-insulator transition

Filled-skuttenudite compounds RM $_4X_{12}$ (R: rare earth, M: Fe, Ru, and Os, and X: P, As, and Sb) with the unique body-centered cubic structures have attracted much interest due to wide variety of physical phenom ena, e.g.m agnetic and quadrupole ordering, K ondo insulating behavior, unconventional superconductivity, etc.^{1,2}

Recently, anom alous phase transition from param agnetic m etal (PM) to spin density wave (SDW) state was found at T = 0.8K in CeO s_4Sb_{12} . Surprisingly, the phase boundary is shifted to higher tem peratures by applying the external magnetic eld²,³ Such increase of the transition tem perature have been often observed in the system s with quadrupole-ordering, 4 but the magnetic measurement⁵ suggests that the crystal-eld (CF) ground state of f electron is 7 which has no quadrupole moment, and the speci c heat measurement shows only a small entropy change at the transition, excluding bcalm om ent ordering but suggesting an SDW or CDW transitions with an opening of a gap over a small portion of the Ferm i surfaces of itinerant electronic states. The neutron scattering experiment⁶ was done but the CF was not clearly observed. The NQR measurements⁷ claims the st-order transition since the hysterisis was observed, but the speci c heat data clearly show peaks at the transition indicating the second order transition with som e short range order.

CeO $s_4 Sb_{12}$ shows sem iconducting behavior in the resistivity experiment with a small charge gap (E $_{\rm g}$ 10K) at low temperatures.⁵ The overall structure of the optical conductivity and its temperature dependence show similar behaviors to those of CeR $u_4 Sb_{12}$ which exhibits a pseudo-gap and the mid-infrared peak with strong temperature-dependence.^{8,9} A lthough the band structure of CeO $s_4 Sb_{12}$ obtained by the band calculation is quite similar to that of CeR $u_4 Sb_{12}$, 10 CeO $s_4 Sb_{12}$ shows sem iconducting behavior, whereas CeR $u_4 Sb_{12}$ is metallic in experiment.⁵

In this letter, we construct the e ective model with the characteristic feature of the led skutterudite compound C eO s₄Sb₁₂ and investigate the anom alous metal-insulator transition observed in this material.

The basic crystal structure of led skuttenudites is that the X_{12} clusters, led by R in the center, form the

body-centered cubic (BCC) lattice. The forbitals of rareearth atom s strongly hybridize with the p orbitals in X $_{12}$ clusters close the Ferm i level. The X $_{12}$ cluster has the T $_{\rm h}$ sym m etry, but its e ect on J= 5/2 f state in Ce is the same as O $_{\rm h}$.

In order to investigate the properties of Ceskuttenudites, we previously proposed a simplified tightbinding band model for CeR u_4 Sb₁₂ consisting of the single valence band and the seven fstates with the spin-orbit interaction and under the cubic crystalline eld¹¹. The form er is represented by the top-most one of the valence bands made up of the p-orbitals on X₁₂ clusters, and has the A_u symmetry which hybridizes with the f-state in the cluster center. The Coulomb interaction was introduced to all the band equally to make the use of the dynamical mean-eld approximation possible.

Here, we simplify the model further to investigate the magnetic properties of CeO s_4Sb_{12} . The present model consists of a single f band (representing the J=5/2, 7 ground states) and a single valence band (the above-mentioned A_u band), hybridizing with each other. Then H am iltonian is given by

where $c_{k_i}^y$ ($f_{k_i}^y$) creates a conduction (f) electron with the momentum k and pseudo-spin (representing 7 doublet), and $n_1^f = f_{1;}^y f_{1;}$ with the site index i. We have assumed the BCC tight-binding band with nearest and next-nearest hopping for conduction band, $c_k^c =$ c_k^k , where $t_k = \cos(k_x a=2)\cos(k_y a=2)\cos(k_z a=2) +$ $2[\cos(k_x a) + \cos(k_y a) + \cos(k_z a)]$. The lattice constant a is set equal to unity in the following. c_i and c_i determine the hopping am plitude. The f state is assumed to have the dispersion $c_k^f = E_f + c_k$, namely the dispersive part is proportional to c_k^c but with a sm all coe cient f. This would be a reasonable choice since both X₁₂ and R oc-

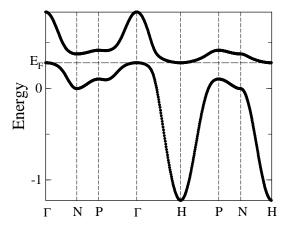


Fig. 1. The band structure for the non-interacting system without the external eld where c=1.0, f=0.03, 2=0.07, $E_f=0.3$, and V = 0.15. E_F represents the Ferm i level.

cupy the same BCC sites.V is the hybridization between conduction and felectrons. Its k-dependence is neglected. These choice of ourm odel band im mensely facilitates the calculations for the strong correlation, which will be reported in a separate paper.¹² Actually, of course, the f-dispersion is created through the $\rm X_{12}$ clusters, so that it must be self-consistently determined with $\frac{c}{k}$ and the hybridization $V_k \cdot U$ is the Coulom b repulsion between f electrons. It is well-known that ${}_{k}^{c}$ and ${}_{k}^{t}$ have perfect nesting characters for $_2 = 0$, V = 0, and at half-lling. The last term in eq. (1) represents the Zeem an energy, where B_{ext} denotes the external magnetic eld along the z direction and is coe cient of e ective m agnetic m oment, which corresponds to $g_J h J_z^f i = 6/7 5/6 = 5/7$ for Ce.

W ithout the C oulom b interaction, the diagonalized energy dispersions are obtained as $E_k = \begin{bmatrix} c \\ k \end{bmatrix} + \begin{bmatrix} t \\ k \end{bmatrix} f(\begin{bmatrix} c \\ k \end{bmatrix})$ $\binom{f}{k}^{2} + 4V^{2}g^{1=2} = 2$, which are the so-called hybridized bands, but since $\frac{f}{k}$ has also a nite dispersion, the two where $\frac{0}{0}$ is the band susceptibility, which is dened by bands can have nite overlap if f is not too sm all.

Considering the empirical trend of the lattice constant and the energy gap of C e-skutterudites, C eO s₄Sb₁₂ m ust be a sem in etal.² Our assum ed band structure is shown in Fig. 1, which has a sem i-m etallic character: the top of lower band (point) and the bottom of upper band (H point) slightly touch the Ferm i level, respectively. The overlapping of the bands is about 0.001 c.

Although our band structure is quite simplied, Fig. 1 captures the low energy structure of the band calculation for $C \in O s_4 S b_{12}^{10}$ rather well. In the published band calculation, 10 one of the band m ade of $_8$ states has a m in im um at point and alm ost touches with the valence band there, but it is neglected here. A lso, only the single valence band is taken into account and the lower bands are completely neglected. These may a ect the quantitative results but at least the qualitative feature may remain unchanged. The existence of $_8$ band may be a cause of the lower tem perature anom aly.

In order to investigate a possibility of a magnetic transition and an anom alous magnetic eld e ect, the random phase approximation (RPA) is employed. Since

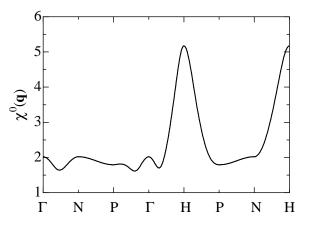


Fig. 2. Static irreducible susceptibility for various m om enta w ithout the external eld at T = 0:002 where ${}^{0}(q) = {}^{0}_{"\#}(q) =$ ${}^{0}_{""}(q) = {}^{0}_{\#\#}(q).$

RPA overestimates the transition temperature, we use the sm all value of the C oulom b interactions here, which is considered as the renorm alized one at the low-energy regime in the rare-earth compounds. Furtherm ore, since the C oulom b interaction acts only on felectrons, ordered states will be mainly determined by the localized felectrons, so that only the f-f component of the correlation function is considered, for simplicity. It is essential for the following theory to calculate both the parallel and perpendicular elements to the external eld of the static susceptibility, which are given by

$$f'(q) = {}^{y}(q) = \frac{2}{2} \frac{{}^{0}_{\pi_{\#}}(q)}{1 \quad U \quad {}^{0}_{\pi_{\#}}(q)}; \qquad (2)$$

$$(\mathbf{q}) = \frac{2}{4} \frac{\int_{\mathbf{n}_{\#}}^{0} (\mathbf{q}) + \int_{\#\#}^{0} (\mathbf{q}) + 2U \int_{\#\#}^{0} (\mathbf{q}) \int_{\#\#}^{0} (\mathbf{q})}{1 \int_{\mathbf{q}}^{0} \int_{\#\#}^{0} (\mathbf{q}) \int_{\#\#}^{0} (\mathbf{q})} (\mathbf{q})$$

$${}^{0} \circ (q) = \frac{T}{N} \sum_{k;!_{n}}^{X} g^{f} (k + q; i!_{n}) g^{f} \circ (k; i!_{n}); (4)$$

$$g^{f}(k; i!_{n}) = \frac{1}{i!_{n} + \frac{f}{k} \frac{V^{2}}{i!_{n} + \frac{c}{k}}}:(5)$$

T is the tem perature and N is the number of sites. is the chemical potential and $!_n (= (2n + 1) T)$ represents the odd M atsubara frequency. $_k^{\rm c}~$ and $_k^{\rm f}~$ are the energy dispersion with the Zeem an term s. Note that we use the following relation that # (q) is always equal to # (q) within the RPA to derive x.

W e num erically calculate the above-m entioned equations. The sum mations are e ciently carried out by using the fast Fourier transform with N = 128 128 128 points in the k sum m ation and 4096 M atsubara frequencies in the $!_n$ sum m ation. Note that hopping am plitude c is taken to be unity for sim plicity.

To discuss the instability to ordered states, the band susceptibility, ⁰(q) ${}^{0}_{""}(q) = {}^{0}_{\#\#}(q) = {}^{0}_{"\#}(q)$ for $B_{ext}=0$, is shown in Fig. 2. The largest value appears

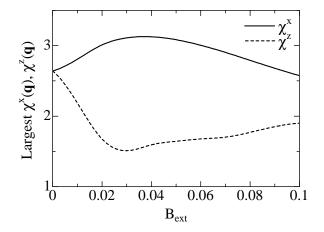


Fig. 3. The largest susceptibilities as a function of the m agnetic eld at T = 0.002 and U = 0.0. Solid (dashed) line represents x (q) (z(q)).

at H point q= (1;0;0) in unit of 2 =a. Since the Ferm i surfaces of electrons and holes are quite sm all spheres, the peak of 0 (q) appears at q = (1;0;0) at low tem – peratures, which corresponds to the di erence between the top of lower band (point) and the bottom of upper band (H point) in Fig. 1. Recently, the result of the neutron scattering for C eO s₄Sb₁₂ at B_{ext} = 0 found that the nesting vector corresponds to q = (1;0;0).¹³ Therefore our obtained result of the susceptibilities is consistent with the experiment at B_{ext} = 0.

The basic lattice structure of CeO s_4Sb_{12} is BCC. For the single band Hubbard model at half-lling with only the nearest neighbor hopping, there exists the perfect nesting at the wave vector q = (1;0;0). In that case, it is known that the in nitesim ally smallU causes the metal-SDW transition at T = 0.A lthough the perfect nesting is lost in the present model due to the hybridization and the next nearest neighbor hoppings, the Ferm i surfaces are in the vicinity of the nesting. Therefore, when the external eld is absent, the metal-SDW transition occurs at U_c 0.2 at T = 0.002 within the RPA in the present model.

Next, let us discuss e ects due to the external magnetic eld. The eld dependence of the largest values of susceptibilities is shown in Fig. 3. W ith increasing the magnetic eld along the z direction, \times is rst enhanced at small eld region. As the external eld is increased further, \times is suppressed. The vector q which gives the largest values of susceptibilities does not change within $B_{ext} < 0.2$. In contrast to the behavior of \times , z is rst suppressed. This behavior is reasonable since when the weak external eld is applied, the spin-spin correlation functions along the external eld are generally suppressed. Furtherm ore, with increasing the external eld further, maximum value of z is enhanced. In this range of eld, the vector q which gives them aximum of the susceptibilities is gradually changed. B oth of susceptibilities

ceptibilities is gradually changed. B oth of susceptibilities are suppressed under larger external eld (not shown). These behaviors and the mechanism s are similar to our previous theory for $C \in R h \ln_5$ where more precise FLEX

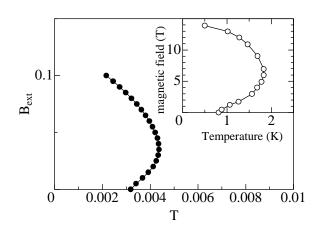


Fig. 4. The T-B Phase diagram of the metal-SDW transition at U = 0.2. The inset shows the experimental result obtained by Sugawara et al.²

(uctuation-exchange) m ethod was used.

In general, the response functions are strongly a ected by the form of Ferm isurface. The present band structure at $B_{ext} = 0$ is close to the perfect nesting, so that the change of m agnetic susceptibilities become sequite large for the external eld. Therefore, it is possible that when the weak external eld is applied, the nesting condition is rather in proved because one of the spin band is shifted by the eld and approaches the nesting condition.

These results indicate that the presence of the external eld enhances instability for ordered states. In the 3-dimensional system, ordered states can occur at nite tem perature. Namely, the anom alous metalа insulator transition m ay occur in the present m odel with appropriate value of the Coulomb repulsion. Figure 4 shows the tem perature-external eld phase diagram of metal-SDW transition. Note that the instability occurs not in ^z (q= (1;0;0)) but in ^x (q= (1;0;0)) (and ^y), which indicates the appearance of the magnetic moment component perpendicular to the eld. It can be checked by an experiment in a future. In the smallexternal eld region, the phase transition tem perature T_N is enhanced with increasing B_{ext} , so that the slope of phase boundary becom es positive. Thus the anom alous phase transition observed in CeO s_4 Sb₁₂ can be qualitatively reproduced.

Note here that in order to calculate m agnetic susceptibilities, we employ the RPA, which is insu cient to take the e ect of quantum uctuations into account. Quantum uctuations particularly become important in the vicinity of quantum critical points where antiferrom agnetic correlations are enhanced.¹⁴ However, correlation e ects are essential in the weak external eld region. By taking quantum uctuations into account e.g. via FLEX approximation,¹⁴ them etal-SDW transition temperature is reduced and the transition boundary as a whole shifts to the low temperature region. In particular, the shift becomes conspicuous at the weak external eld region. However, overall structure of the phase boundary obtained here may not qualitatively changed.

Furtherm ore, we comment the multi-band e ects of f orbitals. In our model, we neglect the degeneracy of f

orbitals, for simplicity. However, in the published band calculation, one of the bands made from the 4f $_8$ states has a minimum at point, though slightly above E_F , which is neglected in our model. However, we consider that the nesting property between the top of the valence band at and the bottom of the $_7$ band at H is the main source of the SDW transition and anom alous phase diagram . Therefore qualitative properties of C eO $s_4 \, \rm Sb_{12}$ can be reproduced by using the present simple model.

A similar anom alous magnetic eld e ect is also investigated for the K ondo insulator, 15,16 in which the ordered phase appears at nite eld since the perpendicular elem ent of spin-spin correlations to the external eld is enhanced.

In sum m ary, we investigate the anom alous phase transition observed in $CeO s_4Sb_{12}$. By constructing the effective tight-binding model with the Coulomb interaction between felectrons, whose band structure is in the vicinity of the nesting, the metal-SDW phase boundary is determined within the mean eld approximation. The nesting condition of Fermi surfaces is improved when the weak external eld is applied, so that the slope of metal-SDW phase boundary becomes positive and the anom alous transition can be reproduced. A small moment perpendicular to the applied magnetic eld should be induced, which can be checked by a future experiment.

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